CONTENT (MLCC)

E STANDARD NUMBER **3**

STRUCTURE **4**

ORDERING CODE **4**

HIGH Q & LOW ESR TYPE (Q SERIES) 5

TEST SPEC. 10

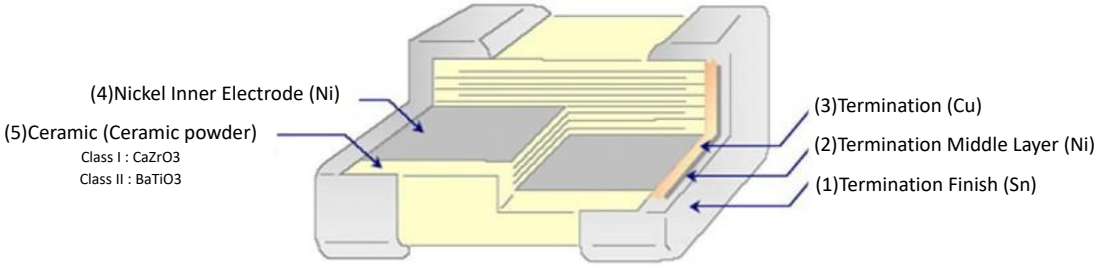
PACKAGE **12**

OTHERS **14**

E Standard Number

E3	1.0								2.2								4.7							
E6	1.0				1.5				2.2				3.3				4.7				6.8			
E12	1.0		1.2		1.5		1.8		2.2		2.7		3.3		3.9		4.7		5.6		6.8		8.2	
E24	1.0	1.1	1.2	1.3	1.5	1.6	1.8	2.0	2.2	2.4	2.7	3.0	3.3	3.6	3.9	4.3	4.7	5.1	5.6	6.2	6.8	7.5	8.2	9.1

Structure



Ordering Code

C 1005 NP0 101 J G T Q

PRODUCT CODE

C = MLCC

SIZE in mm (EIA CODE, in inch)

0402(01005)	0603(0201)	1005 (0402)	1608 (0603)	2012 (0805)
3216 (1206)	3225(1210)	4520 (1808)	4532 (1812)	

T. C.

NP0: 0 ± 30ppm/℃	-55℃ to +125℃		
X7R: ±15%	-55℃ to +125℃	X6S: ±22%	-55℃ to +105℃
X5R: ±15%	-55℃ to +85℃	Y5V: +22%/-82%	-30℃ to +85℃

CAPACITANCE CODE

Expressed in pico-farads and identified by a three-digit number.
First two digits represent significant figures.
Last digit specifies the number of zeros.
(Use 9 for 1.0 through 9.9pF； Use 8 for 0.20 through 0.99pF)

Examples:

Code	Cap (pF)
478	0.47
229	2.2
101	100
102	1000

TOLERANCE CODE

A: ± 0.05pF	B: ± 0.1pF	C: ± 0.25pF	D: ± 0.5pF	F: ±1%	G: ±2%
J: ±5%	K: ±10%	M: ±20%	Z: +80/-20%		

VOLTAGE CODE

B: 4V	C: 6.3V	D: 10V	E: 16V	F: 25V	N: 35V	G: 50V	H: 100V
J: 200V	K: 250V	L: 500V	M: 630V	P: 1KV	Q: 2KV	R: 3KV	S: 4KV

PACKAGING CODE

T: Paper tape reel Ø180mm (7”)
A: Paper tape reel Ø330mm (13”)
W: Special Packing
P: Embossed tape reel Ø180mm (7”)
E: Embossed tape reel Ø330mm (13”)

Application Code

S: Standard Q: High Q/Low ESR F: Microwave A: Automotive Infotainment with AEC-Q200

High Q & Low ESR Type (Q Series)

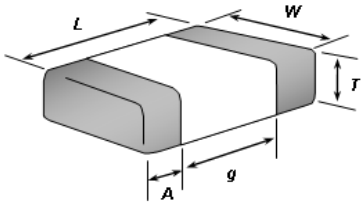
■ Feature

1. Ultra-stable
2. Tight tolerance available
3. Low ESR (Frequency is within 2.4GHz)
4. Good frequency performance
5. No aging of capacitance
6. RoHS compliant
7. Halogen Free
8. MSL Class : MSL 1

■ Application

1. LC and RC tuned circuit
2. Filtering
3. Timing

■ Standard External Dimensions



TYPE (EIA Size)	Dimension (mm)				
	L (Length)	W (Width)	T(Thickness)	g (Min)	A (Min/Max)
C0603 (0201)	0.6±△	0.3±△	△	0.15	0.10 / 0.20
C1005 (0402)	1.0±△	0.5±△		0.30	0.15 / 0.35
C1608 (0603)	1.6±△	0.8±△		0.50	0.25 / 0.65
C2012 (0805)	2.0±△	1.25±△		0.70	0.25 / 0.75
△:Please refer to "Part Number & Characteristic"					

■ Part Number & Characteristic

● C0603NP0_Q Series (EIA0201)

RV	DARFON P/N	Measuring Condition	Capacitance		Available Tolerance	Thick. (mm)	Tolerance(mm)		Testing Freq	ESR mΩ (max.)	Q (min.)	Standard Packing
			Value	Unit			L/W	Thick.				
100V	C0603NP0229□HTQ	1V, 1MHz	2.2	pF	±0.25pF, ±0.1pF	0.30	±0.03	±0.03	1GHz	289	250	Paper, 15Kpcs
	C0603NP0339□HTQ	1V, 1MHz	3.3	pF	±0.25pF, ±0.1pF	0.30	±0.03	±0.03	1GHz	241	200	
	C0603NP0569□HTQ	1V, 1MHz	5.6	pF	±0.25pF, ±0.1pF	0.30	±0.03	±0.03	1GHz	158	180	
50V	C0603NP0108CGTQ	1V, 1MHz	0.1	pF	±0.25pF	0.30	±0.03	±0.03	1GHz	4547	350	Paper, 15Kpcs
	C0603NP0208□GTQ	1V, 1MHz	0.2	pF	±0.25pF, ±0.1pF, ±0.05pF	0.30	±0.03	±0.03	1GHz	2274	350	
	C0603NP0308□GTQ	1V, 1MHz	0.3	pF	±0.25pF, ±0.1pF, ±0.05pF	0.30	±0.03	±0.03	1GHz	1516	350	
	C0603NP0408□GTQ	1V, 1MHz	0.4	pF	±0.25pF, ±0.1pF, ±0.05pF	0.30	±0.03	±0.03	1GHz	1137	350	
	C0603NP0508□GTQ	1V, 1MHz	0.5	pF	±0.25pF, ±0.1pF, ±0.05pF	0.30	±0.03	±0.03	1GHz	909	350	
	C0603NP0608□GTQ	1V, 1MHz	0.6	pF	±0.25pF, ±0.1pF, ±0.05pF	0.30	±0.03	±0.03	1GHz	758	350	
	C0603NP0708□GTQ	1V, 1MHz	0.7	pF	±0.25pF, ±0.1pF, ±0.05pF	0.30	±0.03	±0.03	1GHz	650	350	
	C0603NP0758□GTQ	1V, 1MHz	0.75	pF	±0.25pF, ±0.1pF, ±0.05pF	0.30	±0.03	±0.03	1GHz	606	350	
	C0603NP0808□GTQ	1V, 1MHz	0.8	pF	±0.25pF, ±0.1pF, ±0.05pF	0.30	±0.03	±0.03	1GHz	568	350	
	C0603NP0908□GTQ	1V, 1MHz	0.9	pF	±0.25pF, ±0.1pF, ±0.05pF	0.30	±0.03	±0.03	1GHz	505	350	
	C0603NP0109□GTQ	1V, 1MHz	1.0	pF	±0.25pF, ±0.1pF, ±0.05pF	0.30	±0.03	±0.03	1GHz	455	350	
	C0603NP0119□GTQ	1V, 1MHz	1.1	pF	±0.25pF, ±0.1pF, ±0.05pF	0.30	±0.03	±0.03	1GHz	482	300	
	C0603NP0129□GTQ	1V, 1MHz	1.2	pF	±0.25pF, ±0.1pF, ±0.05pF	0.30	±0.03	±0.03	1GHz	442	300	
	C0603NP0139□GTQ	1V, 1MHz	1.3	pF	±0.25pF, ±0.1pF, ±0.05pF	0.30	±0.03	±0.03	1GHz	408	300	
	C0603NP0149□GTQ	1V, 1MHz	1.4	pF	±0.25pF, ±0.1pF, ±0.05pF	0.30	±0.03	±0.03	1GHz	379	300	
	C0603NP0159□GTQ	1V, 1MHz	1.5	pF	±0.25pF, ±0.1pF, ±0.05pF	0.30	±0.03	±0.03	1GHz	354	300	
	C0603NP0169□GTQ	1V, 1MHz	1.6	pF	±0.25pF, ±0.1pF, ±0.05pF	0.30	±0.03	±0.03	1GHz	332	300	
	C0603NP0179□GTQ	1V, 1MHz	1.7	pF	±0.25pF, ±0.1pF, ±0.05pF	0.30	±0.03	±0.03	1GHz	312	300	
	C0603NP0189□GTQ	1V, 1MHz	1.8	pF	±0.25pF, ±0.1pF, ±0.05pF	0.30	±0.03	±0.03	1GHz	295	300	
	C0603NP0209□GTQ	1V, 1MHz	2.0	pF	±0.25pF, ±0.1pF, ±0.05pF	0.30	±0.03	±0.03	1GHz	318	250	
	C0603NP0229□GTQ	1V, 1MHz	2.2	pF	±0.25pF, ±0.1pF, ±0.05pF	0.30	±0.03	±0.03	1GHz	289	250	
	C0603NP0249□GTQ	1V, 1MHz	2.4	pF	±0.25pF, ±0.1pF, ±0.05pF	0.30	±0.03	±0.03	1GHz	265	250	
	C0603NP0259□GTQ	1V, 1MHz	2.5	pF	±0.25pF, ±0.1pF, ±0.05pF	0.30	±0.03	±0.03	1GHz	255	250	
	C0603NP0279□GTQ	1V, 1MHz	2.7	pF	±0.25pF, ±0.1pF, ±0.05pF	0.30	±0.03	±0.03	1GHz	236	250	
	C0603NP0309□GTQ	1V, 1MHz	3.0	pF	±0.25pF, ±0.1pF, ±0.05pF	0.30	±0.03	±0.03	1GHz	265	200	
	C0603NP0339□GTQ	1V, 1MHz	3.3	pF	±0.25pF, ±0.1pF, ±0.05pF	0.30	±0.03	±0.03	1GHz	241	200	
	C0603NP0369□GTQ	1V, 1MHz	3.6	pF	±0.25pF, ±0.1pF, ±0.05pF	0.30	±0.03	±0.03	1GHz	221	200	
	C0603NP0399□GTQ	1V, 1MHz	3.9	pF	±0.25pF, ±0.1pF, ±0.05pF	0.30	±0.03	±0.03	1GHz	204	200	
	C0603NP0409CGTQ	1V, 1MHz	4.0	pF	±0.25pF	0.30	±0.03	±0.03	1GHz	199	200	
	C0603NP0439□GTQ	1V, 1MHz	4.3	pF	±0.25pF, ±0.1pF, ±0.05pF	0.30	±0.03	±0.03	1GHz	185	200	
	C0603NP0479□GTQ	1V, 1MHz	4.7	pF	±0.25pF, ±0.1pF, ±0.05pF	0.30	±0.03	±0.03	1GHz	169	200	

DARFON

RV	DARFON P/N	Measuring Condition	Capacitance		Available Tolerance	Thick. (mm)	Tolerance(mm)		Testing Freq	ESR mΩ (max.)	Q (min.)	Standard Packing
			Value	Unit			L/W	Thick.				
50V	C0603NP0509□GTQ	1V, 1MHz	5.0	pF	±0.5pF, ±0.25pF, ±0.1pF	0.30	±0.03	±0.03	1GHz	177	180	Paper, 15Kpcs
	C0603NP0519□GTQ	1V, 1MHz	5.1	pF	±0.5pF, ±0.25pF, ±0.1pF	0.30	±0.03	±0.03	1GHz	173	180	
	C0603NP0569□GTQ	1V, 1MHz	5.6	pF	±0.5pF, ±0.25pF, ±0.1pF	0.30	±0.03	±0.03	1GHz	158	180	
	C0603NP0609□GTQ	1V, 1MHz	6.0	pF	±0.5pF, ±0.25pF, ±0.1pF	0.30	±0.03	±0.03	1GHz	147	180	
	C0603NP0629□GTQ	1V, 1MHz	6.2	pF	±0.5pF, ±0.25pF, ±0.1pF	0.30	±0.03	±0.03	1GHz	143	180	
	C0603NP0689□GTQ	1V, 1MHz	6.8	pF	±0.5pF, ±0.25pF, ±0.1pF	0.30	±0.03	±0.03	1GHz	130	180	
	C0603NP0709□GTQ	1V, 1MHz	7.0	pF	±0.5pF, ±0.25pF, ±0.1pF	0.30	±0.03	±0.03	1GHz	189	120	
	C0603NP0759□GTQ	1V, 1MHz	7.5	pF	±0.5pF, ±0.25pF, ±0.1pF	0.30	±0.03	±0.03	1GHz	177	120	
	C0603NP0809□GTQ	1V, 1MHz	8.0	pF	±0.5pF, ±0.25pF, ±0.1pF	0.30	±0.03	±0.03	1GHz	166	120	
	C0603NP0829□GTQ	1V, 1MHz	8.2	pF	±0.5pF, ±0.25pF, ±0.1pF	0.30	±0.03	±0.03	1GHz	162	120	
	C0603NP0909□GTQ	1V, 1MHz	9.0	pF	±0.5pF, ±0.25pF, ±0.1pF	0.30	±0.03	±0.03	1GHz	147	120	
	C0603NP0919□GTQ	1V, 1MHz	9.1	pF	±0.5pF, ±0.25pF, ±0.1pF	0.30	±0.03	±0.03	1GHz	146	120	
	C0603NP0100□GTQ	1V, 1MHz	10	pF	±5%, ±2%	0.30	±0.03	±0.03	1GHz	133	120	
	C0603NP0110□GTQ	1V, 1MHz	11	pF	±5%, ±2%	0.30	±0.03	±0.03	1GHz	138	105	
	C0603NP0120□GTQ	1V, 1MHz	12	pF	±5%, ±2%	0.30	±0.03	±0.03	1GHz	147	90	
	C0603NP0130□GTQ	1V, 1MHz	13	pF	±5%, ±2%	0.30	±0.03	±0.03	1GHz	153	80	
	C0603NP0150□GTQ	1V, 1MHz	15	pF	±5%, ±2%	0.30	±0.03	±0.03	1GHz	152	70	
	C0603NP0160□GTQ	1V, 1MHz	16	pF	±5%, ±2%	0.30	±0.03	±0.03	1GHz	166	60	
	C0603NP0180□GTQ	1V, 1MHz	18	pF	±5%, ±2%	0.30	±0.03	±0.03	1GHz	147	60	
	C0603NP0200□GTQ	1V, 1MHz	20	pF	±5%, ±2%	0.30	±0.03	±0.03	1GHz	199	40	
	C0603NP0220□GTQ	1V, 1MHz	22	pF	±5%,±2%,±1%	0.30	±0.03	±0.03	1GHz	207	35	
25V	C0603NP0108□FTQ	1V, 1MHz	0.1	pF	±0.25pF, ±0.1pF, ±0.05pF	0.30	±0.03	±0.03	1GHz	4547	350	Paper, 15Kpcs
	C0603NP0208□FTQ	1V, 1MHz	0.2	pF	±0.25pF, ±0.1pF, ±0.05pF	0.30	±0.03	±0.03	1GHz	2274	350	
	C0603NP0308□FTQ	1V, 1MHz	0.3	pF	±0.25pF, ±0.1pF, ±0.05pF	0.30	±0.03	±0.03	1GHz	1516	350	
	C0603NP0408□FTQ	1V, 1MHz	0.4	pF	±0.25pF, ±0.1pF, ±0.05pF	0.30	±0.03	±0.03	1GHz	1137	350	
	C0603NP0508□FTQ	1V, 1MHz	0.5	pF	±0.25pF, ±0.1pF, ±0.05pF	0.30	±0.03	±0.03	1GHz	909	350	
	C0603NP0608□FTQ	1V, 1MHz	0.6	pF	±0.25pF, ±0.1pF, ±0.05pF	0.30	±0.03	±0.03	1GHz	758	350	
	C0603NP0708□FTQ	1V, 1MHz	0.7	pF	±0.25pF, ±0.1pF, ±0.05pF	0.30	±0.03	±0.03	1GHz	650	350	
	C0603NP0758□FTQ	1V, 1MHz	0.75	pF	±0.25pF, ±0.1pF, ±0.05pF	0.30	±0.03	±0.03	1GHz	606	350	
	C0603NP0808□FTQ	1V, 1MHz	0.8	pF	±0.25pF, ±0.1pF, ±0.05pF	0.30	±0.03	±0.03	1GHz	568	350	
	C0603NP0908□FTQ	1V, 1MHz	0.9	pF	±0.25pF, ±0.1pF, ±0.05pF	0.30	±0.03	±0.03	1GHz	505	350	
	C0603NP0109□FTQ	1V, 1MHz	1.0	pF	±0.25pF, ±0.1pF, ±0.05pF	0.30	±0.03	±0.03	1GHz	455	350	
	C0603NP0119□FTQ	1V, 1MHz	1.1	pF	±0.25pF, ±0.1pF, ±0.05pF	0.30	±0.03	±0.03	1GHz	482	300	
	C0603NP0129□FTQ	1V, 1MHz	1.2	pF	±0.25pF, ±0.1pF, ±0.05pF	0.30	±0.03	±0.03	1GHz	442	300	
	C0603NP0139□FTQ	1V, 1MHz	1.3	pF	±0.25pF, ±0.1pF, ±0.05pF	0.30	±0.03	±0.03	1GHz	408	300	
	C0603NP0149□FTQ	1V, 1MHz	1.4	pF	±0.25pF, ±0.1pF, ±0.05pF	0.30	±0.03	±0.03	1GHz	379	300	
	C0603NP0159□FTQ	1V, 1MHz	1.5	pF	±0.25pF, ±0.1pF, ±0.05pF	0.30	±0.03	±0.03	1GHz	354	300	
	C0603NP0169□FTQ	1V, 1MHz	1.6	pF	±0.25pF, ±0.1pF, ±0.05pF	0.30	±0.03	±0.03	1GHz	332	300	
	C0603NP0189□FTQ	1V, 1MHz	1.8	pF	±0.25pF, ±0.1pF, ±0.05pF	0.30	±0.03	±0.03	1GHz	295	300	
	C0603NP0209□FTQ	1V, 1MHz	2.0	pF	±0.25pF, ±0.1pF, ±0.05pF	0.30	±0.03	±0.03	1GHz	318	250	
	C0603NP0229□FTQ	1V, 1MHz	2.2	pF	±0.25pF, ±0.1pF, ±0.05pF	0.30	±0.03	±0.03	1GHz	289	250	
	C0603NP0249□FTQ	1V, 1MHz	2.4	pF	±0.25pF, ±0.1pF, ±0.05pF	0.30	±0.03	±0.03	1GHz	265	250	
	C0603NP0259□FTQ	1V, 1MHz	2.5	pF	±0.25pF, ±0.1pF, ±0.05pF	0.30	±0.03	±0.03	1GHz	255	250	
	C0603NP0279□FTQ	1V, 1MHz	2.7	pF	±0.25pF, ±0.1pF, ±0.05pF	0.30	±0.03	±0.03	1GHz	236	250	
	C0603NP0309□FTQ	1V, 1MHz	3.0	pF	±0.25pF, ±0.1pF, ±0.05pF	0.30	±0.03	±0.03	1GHz	265	200	
	C0603NP0339□FTQ	1V, 1MHz	3.3	pF	±0.25pF, ±0.1pF, ±0.05pF	0.30	±0.03	±0.03	1GHz	241	200	
	C0603NP0369□FTQ	1V, 1MHz	3.6	pF	±0.25pF, ±0.1pF, ±0.05pF	0.30	±0.03	±0.03	1GHz	221	200	
	C0603NP0399□FTQ	1V, 1MHz	3.9	pF	±0.25pF, ±0.1pF, ±0.05pF	0.30	±0.03	±0.03	1GHz	204	200	
	C0603NP0409□FTQ	1V, 1MHz	4.0	pF	±0.25pF, ±0.1pF, ±0.05pF	0.30	±0.03	±0.03	1GHz	199	200	
	C0603NP0439□FTQ	1V, 1MHz	4.3	pF	±0.25pF, ±0.1pF, ±0.05pF	0.30	±0.03	±0.03	1GHz	185	200	
	C0603NP0479□FTQ	1V, 1MHz	4.7	pF	±0.25pF, ±0.1pF, ±0.05pF	0.30	±0.03	±0.03	1GHz	169	200	
	C0603NP0509□FTQ	1V, 1MHz	5.0	pF	±0.5pF, ±0.25pF, ±0.1pF	0.30	±0.03	±0.03	1GHz	177	180	
	C0603NP0519□FTQ	1V, 1MHz	5.1	pF	±0.5pF, ±0.25pF, ±0.1pF	0.30	±0.03	±0.03	1GHz	173	180	
	C0603NP0569□FTQ	1V, 1MHz	5.6	pF	±0.5pF, ±0.25pF, ±0.1pF	0.30	±0.03	±0.03	1GHz	158	180	
	C0603NP0609□FTQ	1V, 1MHz	6.0	pF	±0.5pF, ±0.25pF, ±0.1pF	0.30	±0.03	±0.03	1GHz	147	180	
	C0603NP0629□FTQ	1V, 1MHz	6.2	pF	±0.5pF, ±0.25pF, ±0.1pF	0.30	±0.03	±0.03	1GHz	143	180	
	C0603NP0689□FTQ	1V, 1MHz	6.8	pF	±0.5pF, ±0.25pF, ±0.1pF	0.30	±0.03	±0.03	1GHz	130	180	
	C0603NP0709□FTQ	1V, 1MHz	7.0	pF	±0.5pF, ±0.25pF, ±0.1pF	0.30	±0.03	±0.03	1GHz	189	120	
	C0603NP0759□FTQ	1V, 1MHz	7.5	pF	±0.5pF, ±0.25pF, ±0.1pF	0.30	±0.03	±0.03	1GHz	177	120	
	C0603NP0829□FTQ	1V, 1MHz	8.2	pF	±0.5pF, ±0.25pF, ±0.1pF	0.30	±0.03	±0.03	1GHz	162	120	
	C0603NP0909□FTQ	1V, 1MHz	9.0	pF	±0.5pF, ±0.25pF, ±0.1pF	0.30	±0.03	±0.03	1GHz	147	120	
	C0603NP0919□FTQ	1V, 1MHz	9.1	pF	±0.5pF, ±0.25pF, ±0.1pF	0.30	±0.03	±0.03	1GHz	146	120	
	C0603NP0959□FTQ	1V, 1MHz	9.5	pF	±0.5pF, ±0.25pF, ±0.1pF	0.30	±0.03	±0.03	1GHz	140	120	
	C0603NP0100□FTQ	1V, 1MHz	10	pF	±5%, ±2%	0.30	±0.03	±0.03	1GHz	133	120	
	C0603NP0110□FTQ	1V, 1MHz	11	pF	±5%, ±2%	0.30	±0.03	±0.03	1GHz	138	105	
	C0603NP0120□FTQ	1V, 1MHz	12	pF	±5%, ±2%	0.30	±0.03	±0.03	1GHz	147	90	
	C0603NP0130□FTQ	1V, 1MHz	13	pF	±5%, ±2%	0.30	±0.03	±0.03	1GHz	153	80	
	C0603NP0150□FTQ	1V, 1MHz	15	pF	±5%, ±2%	0.30	±0.03	±0.03	1GHz	152	70	
	C0603NP0160□FTQ	1V, 1MHz	16	pF	±5%, ±2%	0.30	±0.03	±0.03	1GHz	166	60	
	C0603NP0180□FTQ	1V, 1MHz	18	pF	±5%, ±2%	0.30	±0.03	±0.03	1GHz	147	60	
	C0603NP0200□FTQ	1V, 1MHz	20	pF	±5%, ±2%	0.30	±0.03	±0.03	1GHz	199	40	
	C0603NP0220□FTQ	1V, 1MHz	22	pF	±5%,±2%,±1%	0.30	±0.03	±0.03	1GHz	207	35	

□ Tolerance Code: A=±0.05 pF, B=±0.1pF, C=±0.25pF ,D=±0.5pF, G=±2%, J=±5%; Special tolerance on the request.

● C1005NP0_Q Series (EIA0402)

RV	DARFON P/N	Measuring Condition	Capacitance		Available Tolerance	Thick. (mm)	Tolerance(mm)		Testing Freq	ESR mΩ (max.)	Q (min.)	Standard Packing
			Value	Unit			L/W	Thick.				
100V	C1005NP0308□HTQ	1V, 1MHz	0.3	pF	±0.25pF, ±0.1pF, ±0.05pF	0.50	±0.05	±0.05	1GHz	1768	300	Paper, 10Kpcs
	C1005NP0109□HTQ	1V, 1MHz	1.0	pF	±0.25pF,±0.1pF,±0.05pF	0.50	±0.05	±0.05	1GHz	531	300	
50V	C1005NP0108BGTQ	1V, 1MHz	0.1	pF	±0.1pF	0.50	±0.05	±0.05	1GHz	5305	300	Paper, 10Kpcs
	C1005NP0208□GTQ	1V, 1MHz	0.2	pF	±0.25pF, ±0.1pF, ±0.05pF	0.50	±0.05	±0.05	1GHz	2653	300	
	C1005NP0308□GTQ	1V, 1MHz	0.3	pF	±0.25pF, ±0.1pF, ±0.05pF	0.50	±0.05	±0.05	1GHz	1768	300	
	C1005NP0408□GTQ	1V, 1MHz	0.4	pF	±0.25pF, ±0.1pF, ±0.05pF	0.50	±0.05	±0.05	1GHz	1326	300	
	C1005NP0508□GTQ	1V, 1MHz	0.5	pF	±0.25pF, ±0.1pF, ±0.05pF	0.50	±0.05	±0.05	1GHz	1061	300	
	C1005NP0568□GTQ	1V, 1MHz	0.56	pF	±0.25pF, ±0.1pF, ±0.05pF	0.50	±0.05	±0.05	1GHz	947	300	
	C1005NP0608□GTQ	1V, 1MHz	0.6	pF	±0.25pF, ±0.1pF, ±0.05pF	0.50	±0.05	±0.05	1GHz	884	300	
	C1005NP0708□GTQ	1V, 1MHz	0.7	pF	±0.25pF, ±0.1pF, ±0.05pF	0.50	±0.05	±0.05	1GHz	758	300	
	C1005NP0758□GTQ	1V, 1MHz	0.75	pF	±0.25pF, ±0.1pF, ±0.05pF	0.50	±0.05	±0.05	1GHz	707	300	
	C1005NP0808□GTQ	1V, 1MHz	0.8	pF	±0.25pF, ±0.1pF, ±0.05pF	0.50	±0.05	±0.05	1GHz	663	300	
	C1005NP0828□GTQ	1V, 1MHz	0.82	pF	±0.25pF, ±0.1pF, ±0.05pF	0.50	±0.05	±0.05	1GHz	647	300	
	C1005NP0908□GTQ	1V, 1MHz	0.9	pF	±0.25pF, ±0.1pF, ±0.05pF	0.50	±0.05	±0.05	1GHz	589	300	
	C1005NP0109□GTQ	1V, 1MHz	1.0	pF	±0.25pF, ±0.1pF, ±0.05pF	0.50	±0.05	±0.05	1GHz	531	300	
	C1005NP0119□GTQ	1V, 1MHz	1.1	pF	±0.25pF, ±0.1pF, ±0.05pF	0.50	±0.05	±0.05	1GHz	482	300	
	C1005NP0129□GTQ	1V, 1MHz	1.2	pF	±0.25pF, ±0.1pF, ±0.05pF	0.50	±0.05	±0.05	1GHz	531	250	
	C1005NP0139□GTQ	1V, 1MHz	1.3	pF	±0.25pF, ±0.1pF, ±0.05pF	0.50	±0.05	±0.05	1GHz	490	250	
	C1005NP0159□GTQ	1V, 1MHz	1.5	pF	±0.25pF, ±0.1pF, ±0.05pF	0.50	±0.05	±0.05	1GHz	424	250	
	C1005NP0169□GTQ	1V, 1MHz	1.6	pF	±0.25pF, ±0.1pF, ±0.05pF	0.50	±0.05	±0.05	1GHz	398	250	
	C1005NP0189□GTQ	1V, 1MHz	1.8	pF	±0.25pF, ±0.1pF, ±0.05pF	0.50	±0.05	±0.05	1GHz	354	250	
	C1005NP0209□GTQ	1V, 1MHz	2.0	pF	±0.25pF, ±0.1pF, ±0.05pF	0.50	±0.05	±0.05	1GHz	398	200	
	C1005NP0229□GTQ	1V, 1MHz	2.2	pF	±0.25pF, ±0.1pF, ±0.05pF	0.50	±0.05	±0.05	1GHz	362	200	
	C1005NP0249□GTQ	1V, 1MHz	2.4	pF	±0.25pF, ±0.1pF, ±0.05pF	0.50	±0.05	±0.05	1GHz	332	200	
	C1005NP0259□GTQ	1V, 1MHz	2.5	pF	±0.25pF, ±0.1pF	0.50	±0.05	±0.05	1GHz	318	200	
	C1005NP0279□GTQ	1V, 1MHz	2.7	pF	±0.25pF, ±0.1pF, ±0.05pF	0.50	±0.05	±0.05	1GHz	295	200	
	C1005NP0299□GTQ	1V, 1MHz	2.9	pF	±0.25pF, ±0.1pF, ±0.05pF	0.50	±0.05	±0.05	1GHz	274	200	
	C1005NP0309□GTQ	1V, 1MHz	3.0	pF	±0.25pF, ±0.1pF, ±0.05pF	0.50	±0.05	±0.05	1GHz	265	200	
	C1005NP0339□GTQ	1V, 1MHz	3.3	pF	±0.25pF, ±0.1pF, ±0.05pF	0.50	±0.05	±0.05	1GHz	241	200	
	C1005NP0369□GTQ	1V, 1MHz	3.6	pF	±0.25pF, ±0.1pF, ±0.05pF	0.50	±0.05	±0.05	1GHz	246	180	
	C1005NP0399□GTQ	1V, 1MHz	3.9	pF	±0.25pF, ±0.1pF, ±0.05pF	0.50	±0.05	±0.05	1GHz	227	180	
	C1005NP0409□GTQ	1V, 1MHz	4.0	pF	±0.25pF, ±0.1pF, ±0.05pF	0.50	±0.05	±0.05	1GHz	221	180	
	C1005NP0439□GTQ	1V, 1MHz	4.3	pF	±0.25pF, ±0.1pF	0.50	±0.05	±0.05	1GHz	206	180	
	C1005NP0479□GTQ	1V, 1MHz	4.7	pF	±0.25pF, ±0.1pF, ±0.05pF	0.50	±0.05	±0.05	1GHz	188	180	
	C1005NP0509□GTQ	1V, 1MHz	5.0	pF	±0.5pF, ±0.25pF, ±0.1pF	0.50	±0.05	±0.05	1GHz	212	150	
	C1005NP0519□GTQ	1V, 1MHz	5.1	pF	±0.5pF, ±0.25pF, ±0.1pF	0.50	±0.05	±0.05	1GHz	208	150	
	C1005NP0569□GTQ	1V, 1MHz	5.6	pF	±0.5pF, ±0.25pF, ±0.1pF	0.50	±0.05	±0.05	1GHz	189	150	
	C1005NP0609□GTQ	1V, 1MHz	6.0	pF	±0.5pF, ±0.25pF, ±0.1pF	0.50	±0.05	±0.05	1GHz	177	150	
	C1005NP0629□GTQ	1V, 1MHz	6.2	pF	±0.5pF, ±0.25pF, ±0.1pF	0.50	±0.05	±0.05	1GHz	171	150	
	C1005NP0689□GTQ	1V, 1MHz	6.8	pF	±0.5pF, ±0.25pF, ±0.1pF	0.50	±0.05	±0.05	1GHz	156	150	
	C1005NP0709□GTQ	1V, 1MHz	7.0	pF	±0.5pF, ±0.25pF, ±0.1pF	0.50	±0.05	±0.05	1GHz	227	100	
	C1005NP0759□GTQ	1V, 1MHz	7.5	pF	±0.5pF, ±0.25pF, ±0.1pF	0.50	±0.05	±0.05	1GHz	212	100	
	C1005NP0809□GTQ	1V, 1MHz	8.0	pF	±0.5pF, ±0.25pF, ±0.1pF	0.50	±0.05	±0.05	1GHz	199	100	
	C1005NP0829□GTQ	1V, 1MHz	8.2	pF	±0.5pF, ±0.25pF, ±0.1pF	0.50	±0.05	±0.05	1GHz	194	100	
	C1005NP0909□GTQ	1V, 1MHz	9.0	pF	±0.5pF, ±0.25pF, ±0.1pF	0.50	±0.05	±0.05	1GHz	177	100	
	C1005NP0919□GTQ	1V, 1MHz	9.1	pF	±0.5pF, ±0.25pF, ±0.1pF	0.50	±0.05	±0.05	1GHz	175	100	
	C1005NP0959□GTQ	1V, 1MHz	9.5	pF	±0.5pF, ±0.25pF, ±0.1pF	0.50	±0.05	±0.05	1GHz	186	90	
	C1005NP0100□GTQ	1V, 1MHz	10	pF	±5%, ±2%, ±1%	0.50	±0.05	±0.05	1GHz	199	80	
	C1005NP0110□GTQ	1V, 1MHz	11	pF	±5%, ±2%	0.50	±0.05	±0.05	1GHz	207	70	
	C1005NP0120□GTQ	1V, 1MHz	12	pF	±5%, ±2%	0.50	±0.05	±0.05	1GHz	221	60	
	C1005NP0130□GTQ	1V, 1MHz	13	pF	±5%, ±2%	0.50	±0.05	±0.05	1GHz	245	50	
	C1005NP0150□GTQ	1V, 1MHz	15	pF	±5%, ±2%, ±1%	0.50	±0.05	±0.05	1GHz	265	40	
	C1005NP0160□GTQ	1V, 1MHz	16	pF	±5%, ±2%, ±1%	0.50	±0.05	±0.05	1GHz	284	35	
	C1005NP0180□GTQ	1V, 1MHz	18	pF	±5%, ±2%, ±1%	0.50	±0.05	±0.05	1GHz	295	30	
	C1005NP0200□GTQ	1V, 1MHz	20	pF	±5%, ±2%	0.50	±0.05	±0.05	1GHz	398	20	
	C1005NP0220□GTQ	1V, 1MHz	22	pF	±5%, ±2%	0.50	±0.05	±0.05	1GHz	362	20	
	C1005NP0300□GTQ	1V, 1MHz	30	pF	±5%, ±2%	0.50	±0.05	±0.05	500MHz	295	18	
	C1005NP0330□GTQ	1V, 1MHz	33	pF	±5%, ±2%	0.50	±0.05	±0.05	500MHz	301	16	
	C1005NP0430□GTQ	1V, 1MHz	43	pF	±5%, ±2%	0.50	±0.05	±0.05	500MHz	264	14	
	C1005NP0470□GTQ	1V, 1MHz	47	pF	±5%, ±2%	0.50	±0.05	±0.05	500MHz	339	10	
	C1005NP0560□GTQ	1V, 1MHz	56	pF	±5%, ±2%	0.50	±0.05	±0.05	500MHz	316	9	
	C1005NP0620□GTQ	1V, 1MHz	62	pF	±5%, ±2%	0.50	±0.05	±0.05	500MHz	321	8	
25V	C1005NP0508BFTQ	1V, 1MHz	0.5	pF	±0.1pF	0.50	±0.05	±0.05	1GHz	1061	300	Paper, 10Kpcs
	C1005NP0209BFTQ	1V, 1MHz	2.0	pF	±0.1pF	0.50	±0.05	±0.05	1GHz	398	200	
	C1005NP0479CFTQ	1V, 1MHz	4.7	pF	±0.25pF	0.50	±0.05	±0.05	1GHz	188	180	
16V	C1005NP0109BETQ	1V, 1MHz	1.0	pF	±0.1pF	0.50	±0.05	±0.05	1GHz	531	300	Paper, 10Kpcs

□ Tolerance Code: A=±0.05 pF, B=±0.1pF, C=±0.25pF ,D=±0.5pF, G=±2%, J=±5%; Special tolerance on the request.

● C1608NP0_Q Series (EIA0603)

RV	DARFON P/N	Measuring Condition	Capacitance		Available Tolerance	Thick. (mm)	Tolerance(mm)		Testing Freq	ESR mΩ (max.)	Q (min.)	Standard Packing
			Value	Unit			L/W	Thick.				
250V	C1608NP0308□KTQ	1V, 1MHz	0.3	pF	±0.25pF,±0.1pF, ±0.05pF	0.80	±0.10	±0.10	1GHz	2122	250	Paper, 4Kpcs
	C1608NP0408□KTQ	1V, 1MHz	0.4	pF	±0.25pF,±0.1pF, ±0.05pF	0.80	±0.10	±0.10	1GHz	1592	250	
	C1608NP0508□KTQ	1V, 1MHz	0.5	pF	±0.25pF,±0.1pF, ±0.05pF	0.80	±0.10	±0.10	1GHz	1273	250	
	C1608NP0758□KTQ	1V, 1MHz	0.75	pF	±0.25pF,±0.1pF, ±0.05pF	0.80	±0.10	±0.10	1GHz	849	250	
	C1608NP0808□KTQ	1V, 1MHz	0.8	pF	±0.25pF,±0.1pF, ±0.05pF	0.80	±0.10	±0.10	1GHz	796	250	
	C1608NP0109□KTQ	1V, 1MHz	1.0	pF	±0.25pF,±0.1pF, ±0.05pF	0.80	±0.10	±0.10	1GHz	637	250	
	C1608NP0129□KTQ	1V, 1MHz	1.2	pF	±0.25pF,±0.1pF, ±0.05pF	0.80	±0.10	±0.10	1GHz	663	200	
	C1608NP0159□KTQ	1V, 1MHz	1.5	pF	±0.25pF,±0.1pF, ±0.05pF	0.80	±0.10	±0.10	1GHz	531	200	
	C1608NP0189□KTQ	1V, 1MHz	1.8	pF	±0.25pF,±0.1pF, ±0.05pF	0.80	±0.10	±0.10	1GHz	442	200	
	C1608NP0209□KTQ	1V, 1MHz	2.0	pF	±0.25pF,±0.1pF, ±0.05pF	0.80	±0.10	±0.10	1GHz	531	150	
	C1608NP0229□KTQ	1V, 1MHz	2.2	pF	±0.25pF,±0.1pF, ±0.05pF	0.80	±0.10	±0.10	1GHz	482	150	
	C1608NP0249□KTQ	1V, 1MHz	2.4	pF	±0.25pF,±0.1pF, ±0.05pF	0.80	±0.10	±0.10	1GHz	442	150	
	C1608NP0279□KTQ	1V, 1MHz	2.7	pF	±0.25pF,±0.1pF, ±0.05pF	0.80	±0.10	±0.10	1GHz	393	150	
	C1608NP0309□KTQ	1V, 1MHz	3.0	pF	±0.25pF,±0.1pF, ±0.05pF	0.80	±0.10	±0.10	1GHz	531	100	
	C1608NP0339□KTQ	1V, 1MHz	3.3	pF	±0.25pF,±0.1pF, ±0.05pF	0.80	±0.10	±0.10	1GHz	482	100	
	C1608NP0399□KTQ	1V, 1MHz	3.9	pF	±0.25pF,±0.1pF, ±0.05pF	0.80	±0.10	±0.10	1GHz	408	100	
	C1608NP0479□KTQ	1V, 1MHz	4.7	pF	±0.25pF,±0.1pF, ±0.05pF	0.80	±0.10	±0.10	1GHz	339	100	
	C1608NP0519□KTQ	1V, 1MHz	5.1	pF	±0.25pF,±0.1pF, ±0.05pF	0.80	±0.10	±0.10	1GHz	347	90	
	C1608NP0569□KTQ	1V, 1MHz	5.6	pF	±0.5pF, ±0.25pF,±0.1pF	0.80	±0.10	±0.10	1GHz	355	80	
	C1608NP0609□KTQ	1V, 1MHz	6.0	pF	±0.5pF, ±0.25pF,±0.1pF	0.80	±0.10	±0.10	1GHz	332	80	
	C1608NP0689□KTQ	1V, 1MHz	6.8	pF	±0.5pF, ±0.25pF,±0.1pF	0.80	±0.10	±0.10	1GHz	293	80	
	C1608NP0829□KTQ	1V, 1MHz	8.2	pF	±0.5pF, ±0.25pF,±0.1pF	0.80	±0.10	±0.10	1GHz	277	70	
	C1608NP0919□KTQ	1V, 1MHz	9.1	pF	±0.5pF, ±0.25pF,±0.1pF	0.80	±0.10	±0.10	1GHz	250	70	
	C1608NP0100□KTQ	1V, 1MHz	10	pF	±5%,±2%	0.80	±0.10	±0.10	1GHz	227	70	
	C1608NP0120JKTQ	1V, 1MHz	12	pF	±5%	0.80	±0.10	±0.10	1GHz	332	40	
	C1608NP0150□KTQ	1V, 1MHz	15	pF	±5%,±2%	0.80	±0.10	±0.10	1GHz	303	35	
	C1608NP0180□KTQ	1V, 1MHz	18	pF	±5%,±2%	0.80	±0.10	±0.10	1GHz	295	30	
	C1608NP0220□KTQ	1V, 1MHz	22	pF	±5%,±2%	0.80	±0.10	±0.10	1GHz	289	25	
	C1608NP0101JKTQ	1V, 1MHz	100	pF	±5%	0.80	±0.10	±0.10	500MHz	398	4	
200V	C1608NP0208□JTQ	1V, 1MHz	0.2	pF	±0.25pF,±0.1pF	0.80	±0.10	±0.10	1GHz	3183	250	Paper, 4Kpcs
	C1608NP0129BJTQ	1V, 1MHz	1.2	pF	±0.1pF	0.80	±0.10	±0.10	1GHz	663	200	
	C1608NP0159BJTQ	1V, 1MHz	1.5	pF	±0.1pF	0.80	±0.10	±0.10	1GHz	531	200	
	C1608NP0189BJTQ	1V, 1MHz	1.8	pF	±0.1pF	0.80	±0.10	±0.10	1GHz	442	200	
	C1608NP0229BJTQ	1V, 1MHz	2.2	pF	±0.1pF	0.80	±0.10	±0.10	1GHz	482	150	
	C1608NP0249□JTQ	1V, 1MHz	2.4	pF	±0.25pF,±0.1pF, ±0.05pF	0.80	±0.10	±0.10	1GHz	442	150	
	C1608NP0279BJTQ	1V, 1MHz	2.7	pF	±0.1pF	0.80	±0.10	±0.10	1GHz	393	150	
	C1608NP0309BJTQ	1V, 1MHz	3.0	pF	±0.1pF	0.80	±0.10	±0.10	1GHz	531	100	
	C1608NP0339BJTQ	1V, 1MHz	3.3	pF	±0.1pF	0.80	±0.10	±0.10	1GHz	482	100	
	C1608NP0399BJTQ	1V, 1MHz	3.9	pF	±0.1pF	0.80	±0.10	±0.10	1GHz	408	100	
	C1608NP0439BJTQ	1V, 1MHz	4.3	pF	±0.1pF	0.80	±0.10	±0.10	1GHz	370	100	
	C1608NP0479□JTQ	1V, 1MHz	4.7	pF	±0.25pF,±0.1pF, ±0.05pF	0.80	±0.10	±0.10	1GHz	339	100	
	C1608NP0519□JTQ	1V, 1MHz	5.1	pF	±0.25pF,±0.1pF, ±0.05pF	0.80	±0.10	±0.10	1GHz	347	90	
	C1608NP0689BJTQ	1V, 1MHz	6.8	pF	±0.1pF	0.80	±0.10	±0.10	1GHz	293	80	
	C1608NP0829CJTQ	1V, 1MHz	8.2	pF	±0.25pF	0.80	±0.10	±0.10	1GHz	277	70	
100V	C1608NP0308□HTQ	1V, 1MHz	0.3	pF	±0.25pF,±0.1pF, ±0.05pF	0.80	±0.10	±0.10	1GHz	2122	250	Paper, 4Kpcs
	C1608NP0508□HTQ	1V, 1MHz	0.5	pF	±0.25pF,±0.1pF, ±0.05pF	0.80	±0.10	±0.10	1GHz	1273	250	
	C1608NP0758□HTQ	1V, 1MHz	0.75	pF	±0.25pF,±0.1pF, ±0.05pF	0.80	±0.10	±0.10	1GHz	849	250	
	C1608NP0109□HTQ	1V, 1MHz	1.0	pF	±0.25pF,±0.1pF, ±0.05pF	0.80	±0.10	±0.10	1GHz	637	250	
	C1608NP0129□HTQ	1V, 1MHz	1.2	pF	±0.25pF,±0.1pF, ±0.05pF	0.80	±0.10	±0.10	1GHz	663	200	
	C1608NP0159□HTQ	1V, 1MHz	1.5	pF	±0.25pF,±0.1pF, ±0.05pF	0.80	±0.10	±0.10	1GHz	531	200	
	C1608NP0189□HTQ	1V, 1MHz	1.8	pF	±0.25pF,±0.1pF, ±0.05pF	0.80	±0.10	±0.10	1GHz	442	200	
	C1608NP0209□HTQ	1V, 1MHz	2.0	pF	±0.25pF,±0.1pF, ±0.05pF	0.80	±0.10	±0.10	1GHz	531	150	
	C1608NP0229□HTQ	1V, 1MHz	2.2	pF	±0.25pF,±0.1pF, ±0.05pF	0.80	±0.10	±0.10	1GHz	482	150	
	C1608NP0249□HTQ	1V, 1MHz	2.4	pF	±0.25pF,±0.1pF, ±0.05pF	0.80	±0.10	±0.10	1GHz	442	150	
	C1608NP0279□HTQ	1V, 1MHz	2.7	pF	±0.25pF,±0.1pF, ±0.05pF	0.80	±0.10	±0.10	1GHz	393	150	
	C1608NP0309□HTQ	1V, 1MHz	3.0	pF	±0.25pF,±0.1pF, ±0.05pF	0.80	±0.10	±0.10	1GHz	531	100	
	C1608NP0339□HTQ	1V, 1MHz	3.3	pF	±0.25pF,±0.1pF, ±0.05pF	0.80	±0.10	±0.10	1GHz	482	100	
	C1608NP0399□HTQ	1V, 1MHz	3.9	pF	±0.25pF,±0.1pF, ±0.05pF	0.80	±0.10	±0.10	1GHz	408	100	
	C1608NP0479□HTQ	1V, 1MHz	4.7	pF	±0.25pF,±0.1pF, ±0.05pF	0.80	±0.10	±0.10	1GHz	339	100	
	C1608NP0509□HTQ	1V, 1MHz	5.0	pF	±0.25pF,±0.1pF	0.80	±0.10	±0.10	1GHz	354	90	
	C1608NP0569□HTQ	1V, 1MHz	5.6	pF	±0.5pF, ±0.25pF,±0.1pF	0.80	±0.10	±0.10	1GHz	355	80	
	C1608NP0609□HTQ	1V, 1MHz	6.0	pF	±0.5pF, ±0.25pF,±0.1pF	0.80	±0.10	±0.10	1GHz	332	80	
	C1608NP0689□HTQ	1V, 1MHz	6.8	pF	±0.5pF, ±0.25pF,±0.1pF	0.80	±0.10	±0.10	1GHz	293	80	
	C1608NP0829□HTQ	1V, 1MHz	8.2	pF	±0.5pF, ±0.25pF,±0.1pF	0.80	±0.10	±0.10	1GHz	277	70	
	C1608NP0919□HTQ	1V, 1MHz	9.1	pF	±0.5pF, ±0.25pF,±0.1pF	0.80	±0.10	±0.10	1GHz	250	70	
	C1608NP0100JHTQ	1V, 1MHz	10	pF	±5%	0.80	±0.10	±0.10	1GHz	227	70	
	C1608NP0120□HTQ	1V, 1MHz	12	pF	±5%,±2%,±1%	0.80	±0.10	±0.10	1GHz	332	40	
	C1608NP0150JHTQ	1V, 1MHz	15	pF	±5%	0.80	±0.10	±0.10	1GHz	303	35	
	C1608NP0180JHTQ	1V, 1MHz	18	pF	±5%	0.80	±0.10	±0.10	1GHz	295	30	
	C1608NP0220JHTQ	1V, 1MHz	22	pF	±5%	0.80	±0.10	±0.10	1GHz	289	25	

□ Tolerance Code: A=±0.05 pF, B=±0.1pF, C=±0.25pF ,D=±0.5pF, G=±2%, J=±5%; Special tolerance on the request.

RV	DARFON P/N	Measuring Condition	Capacitance		Available Tolerance	Thick. (mm)	Tolerance(mm)		Testing Freq	ESR mΩ (max.)	Q (min.)	Standard Packing
			Value	Unit			L/W	Thick.				
50V	C1608NP0208□GTQ	1V, 1MHz	0.20	pF	±0.25pF±0.1pF, ±0.05pF	0.80	±0.10	±0.10	1GHz	3183	250	Paper, 4Kpcs
	C1608NP0228□GTQ	1V, 1MHz	0.22	pF	±0.25pF±0.1pF, ±0.05pF	0.80	±0.10	±0.10	1GHz	2894	250	
	C1608NP0308□GTQ	1V, 1MHz	0.30	pF	±0.25pF±0.1pF, ±0.05pF	0.80	±0.10	±0.10	1GHz	2122	250	
	C1608NP0508□GTQ	1V, 1MHz	0.50	pF	±0.25pF±0.1pF, ±0.05pF	0.80	±0.10	±0.10	1GHz	1273	250	
	C1608NP0758□GTQ	1V, 1MHz	0.75	pF	±0.25pF±0.1pF, ±0.05pF	0.80	±0.10	±0.10	1GHz	849	250	
	C1608NP0109□GTQ	1V, 1MHz	1.0	pF	±0.25pF±0.1pF, ±0.05pF	0.80	±0.10	±0.10	1GHz	637	250	
	C1608NP0129□GTQ	1V, 1MHz	1.2	pF	±0.25pF, ±0.1pF	0.80	±0.10	±0.10	1GHz	663	200	
	C1608NP0159□GTQ	1V, 1MHz	1.5	pF	±0.25pF, ±0.1pF	0.80	±0.10	±0.10	1GHz	531	200	
	C1608NP0189□GTQ	1V, 1MHz	1.8	pF	±0.25pF, ±0.1pF	0.80	±0.10	±0.10	1GHz	442	200	
	C1608NP0209□GTQ	1V, 1MHz	2.0	pF	±0.25pF, ±0.1pF	0.80	±0.10	±0.10	1GHz	531	150	
	C1608NP0229□GTQ	1V, 1MHz	2.2	pF	±0.25pF, ±0.1pF	0.80	±0.10	±0.10	1GHz	482	150	
	C1608NP0249□GTQ	1V, 1MHz	2.4	pF	±0.25pF, ±0.1pF	0.80	±0.10	±0.10	1GHz	442	150	
	C1608NP0279□GTQ	1V, 1MHz	2.7	pF	±0.25pF, ±0.1pF	0.80	±0.10	±0.10	1GHz	393	150	
	C1608NP0309□GTQ	1V, 1MHz	3.0	pF	±0.25pF, ±0.1pF	0.80	±0.10	±0.10	1GHz	531	100	
	C1608NP0339□GTQ	1V, 1MHz	3.3	pF	±0.25pF, ±0.1pF	0.80	±0.10	±0.10	1GHz	482	100	
	C1608NP0399□GTQ	1V, 1MHz	3.9	pF	±0.25pF, ±0.1pF	0.80	±0.10	±0.10	1GHz	408	100	
	C1608NP0479□GTQ	1V, 1MHz	4.7	pF	±0.25pF, ±0.1pF	0.80	±0.10	±0.10	1GHz	339	100	
	C1608NP0509□GTQ	1V, 1MHz	5.0	pF	±0.25pF, ±0.1pF	0.80	±0.10	±0.10	1GHz	354	90	
	C1608NP0569□GTQ	1V, 1MHz	5.6	pF	±0.5pF, ±0.25pF, ±0.1pF	0.80	±0.10	±0.10	1GHz	355	80	
	C1608NP0609□GTQ	1V, 1MHz	6.0	pF	±0.5pF, ±0.25pF, ±0.1pF	0.80	±0.10	±0.10	1GHz	332	80	
	C1608NP0689□GTQ	1V, 1MHz	6.8	pF	±0.5pF, ±0.25pF, ±0.1pF	0.80	±0.10	±0.10	1GHz	293	80	
	C1608NP0829□GTQ	1V, 1MHz	8.2	pF	±0.5pF, ±0.25pF, ±0.1pF	0.80	±0.10	±0.10	1GHz	277	70	
	C1608NP0919□GTQ	1V, 1MHz	9.1	pF	±0.5pF, ±0.25pF, ±0.1pF	0.80	±0.10	±0.10	1GHz	250	70	
	C1608NP0100JGTQ	1V, 1MHz	10	pF	±5%	0.80	±0.10	±0.10	1GHz	227	70	
	C1608NP0120□GTQ	1V, 1MHz	12	pF	±5%,±2%,±1%	0.80	±0.10	±0.10	1GHz	332	40	
	C1608NP0150JGTQ	1V, 1MHz	15	pF	±5%	0.80	±0.10	±0.10	1GHz	303	35	
	C1608NP0180JGTQ	1V, 1MHz	18	pF	±5%	0.80	±0.10	±0.10	1GHz	295	30	
	C1608NP0220JGTQ	1V, 1MHz	22	pF	±5%	0.80	±0.10	±0.10	1GHz	289	25	
	C1608NP0470JGTQ	1V, 1MHz	47	pF	±5%	0.80	±0.10	±0.10	500MHz	282	12	

● C2012NP0_Q Series (EIA0805)

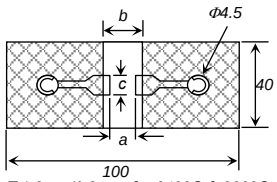
RV	DARFON P/N	Measuring Condition	Capacitance		Available Tolerance	Thick. (mm)	Tolerance(mm)		Testing Freq	ESR mΩ (max.)	Q (min.)	Standard Packing
			Value	Unit			L/W	Thick.				
250V	C2012NP0508□KTQC	1V, 1MHz	0.5	pF	±0.25pF±0.1pF, ±0.05pF	0.60	±0.15/±0.10	±0.10	1GHz	1273	250	Paper, 4Kpcs
	C2012NP0608□KTQC	1V, 1MHz	0.6	pF	±0.25pF±0.1pF, ±0.05pF	0.60	±0.15/±0.10	±0.10	1GHz	1061	250	
	C2012NP0708□KTQC	1V, 1MHz	0.7	pF	±0.25pF±0.1pF, ±0.05pF	0.60	±0.15/±0.10	±0.10	1GHz	909	250	
	C2012NP0808□KTQC	1V, 1MHz	0.8	pF	±0.25pF±0.1pF, ±0.05pF	0.60	±0.15/±0.10	±0.10	1GHz	796	250	
	C2012NP0908□KTQC	1V, 1MHz	0.9	pF	±0.25pF±0.1pF, ±0.05pF	0.60	±0.15/±0.10	±0.10	1GHz	707	250	
	C2012NP0109□KTQC	1V, 1MHz	1.0	pF	±0.25pF±0.1pF, ±0.05pF	0.60	±0.15/±0.10	±0.10	1GHz	637	250	
	C2012NP0129□KTQC	1V, 1MHz	1.2	pF	±0.25pF,±0.1pF	0.60	±0.15/±0.10	±0.10	1GHz	531	250	
	C2012NP0159□KTQC	1V, 1MHz	1.5	pF	±0.25pF,±0.1pF	0.60	±0.15/±0.10	±0.10	1GHz	531	200	
	C2012NP0189□KTQC	1V, 1MHz	1.8	pF	±0.25pF,±0.1pF	0.60	±0.15/±0.10	±0.10	1GHz	442	200	
	C2012NP0229□KTQC	1V, 1MHz	2.2	pF	±0.25pF,±0.1pF	0.60	±0.15/±0.10	±0.10	1GHz	482	150	
	C2012NP0279□KTQC	1V, 1MHz	2.7	pF	±0.25pF,±0.1pF	0.60	±0.15/±0.10	±0.10	1GHz	393	150	
	C2012NP0339□KTQC	1V, 1MHz	3.3	pF	±0.25pF,±0.1pF	0.60	±0.15/±0.10	±0.10	1GHz	482	100	
	C2012NP0399□KTQC	1V, 1MHz	3.9	pF	±0.25pF,±0.1pF	0.60	±0.15/±0.10	±0.10	1GHz	408	100	
	C2012NP0479□KTQC	1V, 1MHz	4.7	pF	±0.25pF,±0.1pF	0.60	±0.15/±0.10	±0.10	1GHz	339	100	
	C2012NP0569□KTQC	1V, 1MHz	5.6	pF	±0.25pF,±0.1pF	0.60	±0.15/±0.10	±0.10	1GHz	355	80	
	C2012NP0689□KTQC	1V, 1MHz	6.8	pF	±0.25pF,±0.1pF	0.60	±0.15/±0.10	±0.10	1GHz	293	80	
	C2012NP0829□KTQC	1V, 1MHz	8.2	pF	±0.25pF,±0.1pF	0.60	±0.15/±0.10	±0.10	1GHz	277	70	
	C2012NP0100□KTQC	1V, 1MHz	10	pF	±5%, ±2%	0.60	±0.15/±0.10	±0.10	1GHz	227	70	
	C2012NP0120□KTQC	1V, 1MHz	12	pF	±5%, ±2%	0.60	±0.15/±0.10	±0.10	1GHz	332	40	
	C2012NP0150□KTQC	1V, 1MHz	15	pF	±5%, ±2%	0.60	±0.15/±0.10	±0.10	1GHz	303	35	

□ Tolerance Code: A=±0.05 pF, B=±0.1pF, C=±0.25pF ,D=±0.5pF, G=±2%, J=±5%; Special tolerance on the request.

Test Spec.

	Item		Specification	Test Method
1	**Operating Temperature Range**		NP0: -55 to 125 ℃	---
2	**Rated Voltage**		Shown in the table of "Part Number & Characteristic"	The rated voltage is defined as the maximum voltage, which may be applied continuously to the capacitor.
3	**Appearance**		No defects or abnormalities.	Visual inspection
4	**Dimensions**		Within the specified dimension.	Using calipers or Microscope.
5	**Dielectric Strength (Flash)**		No defects or abnormalities.	No failure shall be observed when 250% of the rated voltage is applied between the terminations for 1 to 5 seconds. The charge and discharge current is less than 50mA.
6	**Insulation Resistance (I.R.)**		I.R.≧10GΩ	The insulation resistance shall be measured with a DC voltage not exceeding the rated voltage at 25℃ and 75%RH max, and within 1 minute of charging.
7	**Capacitance**		Within the specified tolerance	The capacitance /Q shall be measured at 25℃ at the frequency and voltage shown in the tables. Frequency: 1.0±0.1MHz Voltage: 1.0±0.2Vrms
8	**Quality Factor (Q)**		30pF min.: Q≧1000 30pF max.: Q≧400+20C C: Nominal Capacitance (pF)	
9	**Capacitance Temperature Characteristics**		Capacitance change within 0±30ppm/ ℃ under operating temperature range.	The capacitance value at 25℃ and 85℃ shall be measured and calculated from the formula given below. T.C.=(C_{85}-C_{25})/C_{25}*ΔT*10^6(PPM/℃)
10	**Termination Strength**		No removal of the terminations or marking defect.	Apply a parallel force of 5N to a PCB mounted sample for 10±1sec. *2N for 0603 (EIA 0201).
11	**Deflection (Bending Strength)**		No cracking or marking defects shall occur at 1mm deflection. Capacitance change: NP0: within ±5% or ± 0.5pF. (whichever is larger)	Solder the capacitor to the test jig (glass epoxy boards) shown in Fig.a using a SAC305(Sn96.5Ag3.0Cu0.5) solder. Then apply a force in the direction shown in Fig.b. The soldering shall be done with the reflow method and shall be conducted with care so that the soldering is uniform and free of defects such as heat shock.
12	**Solderability of Termination**		90% of the terminations are to be soldered evenly and continuously. C0402 Series: 75% of the terminations are to be soldered evenly and continuously.	Immerse the test capacitor into a methanol solution containing rosin for 3 to 5 seconds, preheat it 150 to 180℃ for 2 to 3 minutes and immerse it into SAC305(Sn96.5Ag3.0Cu0.5) solder of 245 ± 5℃ for 3±1seconds.
13	**Resistance to Soldering Heat**	**Appearance**	No marking defects	Immerse the capacitor in a SAC305(Sn96.5Ag3.0Cu0.5) solder solution at 270±5℃ for 10±1 seconds. Let sit at room temperature for 24±2 hours, then measure. *C0402 Series is not suitable for this testing
		Cap. Change	NP0 within ±2.5% or ±0.25pF (whichever is larger)	
		Q	Initial spec.	
		I.R.	Initial spec.	

(Unit in mm)



T:1.6mm(0.8 mm for 0402C & 0603C & 1005C size)

Fig. a.

Size	a	b	C
0402	0.2	0.56	0.23
0603	0.3	0.9	0.3
1005	0.4	1.5	0.5
1608	1.0	3.0	1.2

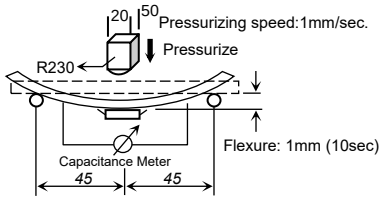


Fig.b.

	Item		Specification	Test Method
14	Temperature cycle (Thermal shock)	Appearance	No marking defects	Solder the capacitor to supporting jig (glass epoxy board) and perform the five cycles according to the four heat treatments listed in the following table. Let sit for 24±2hrs at room temperature, then measure. Step 1: Minimum operating temperature 30±3min Step 2: Room temperature 2~3 min Step 3: Maximum operating temperature 30±3min Step 4: Room temperature 2~3min
		Cap. Change	NP0 within ±2.5% or 0.25pF (whichever is larger)	
		Q	Initial spec.	
		I.R.	Initial spec.	
15	Humidity load	Appearance	No marking defects	Apply the rated voltage at 40±2℃ and 90 to 95% humidity for 500±12 hours. Remove and let sit for 24±2 hours at room temperature, then measure. The charge / discharge current is less than 50mA.
		Cap. Change	NP0 within ±5% or ±0.5pF (whichever is larger)	
		Q	200 min.	
		I.R.	I.R.≧500MΩ	
16	High temperature load life test	Appearance	No marking defects	Apply 200% of the rated voltage for 1000±12 hours at the maximum operating temperature ± 3℃. Let sit for 24± 2 hours at room temperature, then measure. The charge/discharge current is less than 50mA.
		Cap. Change	NP0 within ±5% or ±0.5pF (whichever is larger)	
		Q	30pF and over : Q≧350 10pF and over, 30pF and below : Q≧275+5C/2 10pF and below : Q≧200+10C C:Nominal Capacitance(pF)	
		I.R.	I.R.≧1GΩ	
17	ESR & Q		Shown in the table of “Part Number & Characteristic”	Testing frequency is shown in the table of “Part Number & Characteristic”

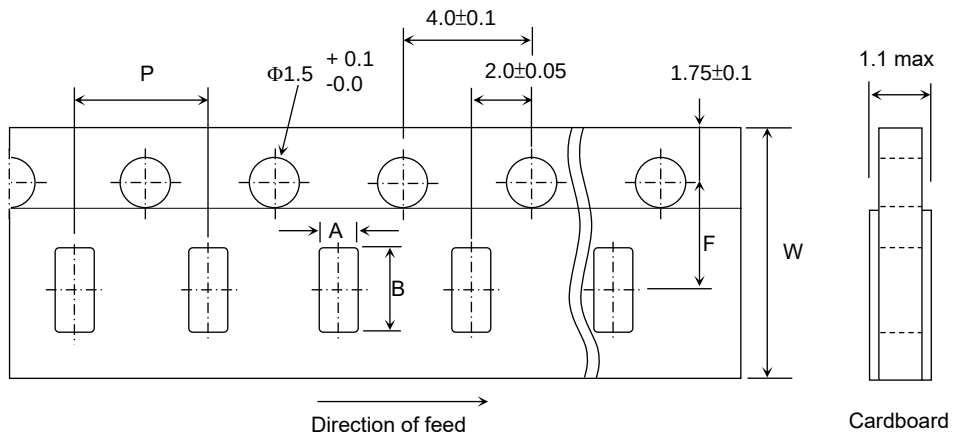
Package

- **Tape and reel packaging**

  Tape and reel packaging is currently the most promising system for high-speed production. A typical 180mm (7 inch) diameter reel contains 1,500 to 15,000 capacitors, 250mm (10 inch) contains 10,000 capacitors, and 330mm (13 inch) contains 10,000 to 50,000 capacitors. Three standard sizes are available in taped and reeled package either with paper carrier tapes or embossed tapes.

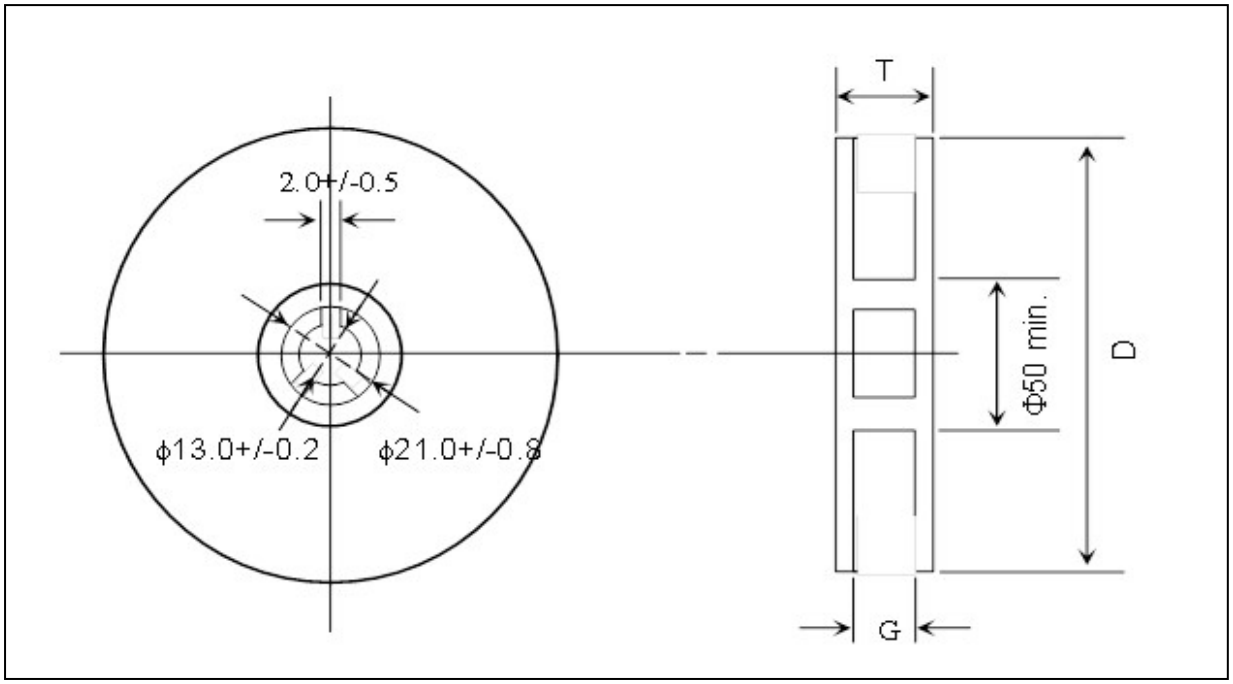
【Paper tape specifications】

2mm and 4mm pitch tape



SYMBOL	PRODUCT SIZE CODE								UNIT
	0603(0201)		1005(0402) (±0.05 mm)		1608 (0603) (±0.10 mm)		C2012 (0805)		
	SIZE	TOL.	SIZE	TOL.	SIZE	TOL.	SIZE	TOL.	
A	0.38	± 0.04	0.65	± 0.10	1.0	±0.2	1.5	±0.2	mm
B	0.68	± 0.04	1.15	± 0.10	1.8	±0.2	2.3	±0.2	mm
F	3.5	± 0.05	3.5	± 0.05	3.5	±0.05	3.5	±0.05	mm
P	2	± 0.10	2	± 0.10	4	±0.1	4	±0.1	mm
W	8	± 0.20	8	± 0.20	8	±0.2	8	±0.2	mm

【Reel specifications】



TAPE WIDTH (mm)	G (mm)	T max. (mm)	D (mm)
8	10.0 ± 1.5	14.5	180
8	10.0 ± 1.5	14.5	330

【Thickness and Packing Amount】

Thickness			Amount per reel			
			180 mm (7")		330 mm (13")	
Code	Spec.(mm)	Size (EIA)	Paper	Embossed	Paper	Embossed
A	0.30	0603 (0201)	15K		50K	
B	0.50	1005 (0402)	10K		50K	
C	0.60	2012 (0805)	4K		15K	
D	0.80	1608 (0603)	4K		15K	
		2012 (0805)	4K		15K	
E	0.85	2012 (0805)	4K		15K	

【Packing Rule】

EIA SIZE	Tape type	Reel Size	Max Reels/Box
0603 (0201)	Paper	7"	10
1005 (0402)	Paper	7"	10
1608 (0603)	Paper/Emboss	7"	10
2012 (0805)	Paper/Emboss	7"	10

*Maximum 60 reels in one carton.

Others

【Storage】

1. The chip capacitors shall be packaged in carrier tapes or bulk cases.
2. Too high temperatures or humidity may deteriorate the quality of the product rapidly. Recommended products storage with temperatures from +5℃ to +35℃, humidity from 45 to 70% RH.
3. The storage atmosphere must be free of gas containing sulfur and chlorine. Also, avoid exposing the product to saline moisture. If the product is exposed to such atmospheres, the terminations will oxidize and solderability will be affected.
4. In consideration of solderability, an allowable storage period should be within 12 months from the outgoing date of delivery. As for products in storage over 12 months, please check solderability before use.

【Circuit Design】

1. Once application and assembly environments have been checked, the capacitor may be used in conformance with the rating and performance, which are provided in both the catalog and the specifications. Exceeding the specifications listed may result in inferior performance. It may also cause a short, open, smoking, or flaming to occur, etc.
2. Please use the capacitors in conformance with the operating temperature provided in both the catalog and the specifications. Be especially cautious not to exceed the maximum temperature. In the situation the maximum temperature set forth in both the catalog and specifications is exceeded, the capacitor's insulation resistance may deteriorate, power may suddenly surge and short-circuit may occur. The loss of capacitance will occur, and may self-heat due to equivalent series resistance when alternating electric current is passed through. As this effect becomes critical in high frequency circuits, please exercise with caution. When using the capacitor in a (self-heating) circuit, please make sure the surface of the capacitor remains under the maximum temperature for usage. Also, please make certain temperature rise remain below 20℃.
3. Please keep voltage under the rated voltage, which is applied to the capacitor. Also, please make certain the peak voltage remains below the rated voltage when AC voltage is super-imposed to the DC voltage. In the situation where AC or pulse voltage is employed, ensure average peak voltage does not exceed the rated voltage. Exceeding the rated voltage provided in both catalog and specifications may lead to defective withstanding voltage or, in worse case situations, may cause the capacitor to burn out.
4. It's is a common phenomenon of high-dielectric products to have a deteriorated amount of static electricity due to the application of DC voltage.

【Handling】

Chip capacitors should be handled with care to avoid contamination or damage. The use of vacuum pick-up or plastic tweezers is recommended for manual placement. Tape and reeled packages are suitable for automatic pick and placement machine.

【Flux】

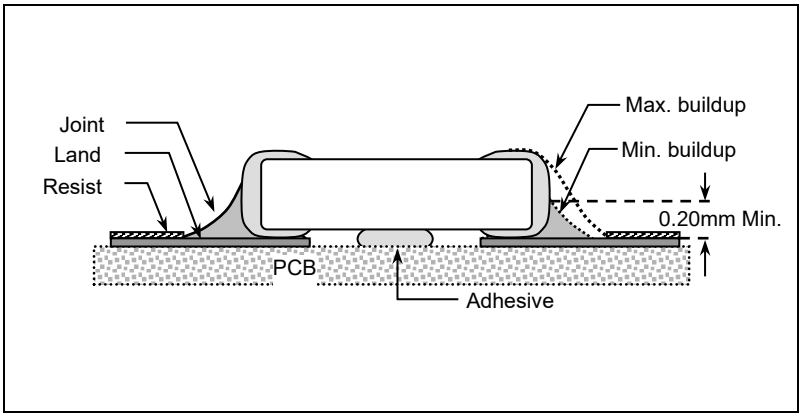
1. An excessive amount of flux or too rapid temperature rise can causes solvent burst, solder can generate a large quantity of gas. The gas can spreads small solder particles to cause solder balling effect or bridging problem.
2. Flux containing too high of a percentage of halide may cause corrosion of termination unless sufficient cleaning is applied.
3. Use rosin-type flux. Highly acidic flux (halide content less than 0.2wt%) is not recommended.
4. The water soluble flux causes deteriorated insulation resistance between outer terminations unless sufficiently cleaned.

【Component Spacing】

For wave soldering components, the spacing must be sufficient far apart to prevent bridging or shadowing. This is not so important for reflow process but enough space for rework should be considered. The suggested spacing for reflow soldering and wave soldering is 0.5mm and 1.0mm, respectively.

【Solder Fillet】

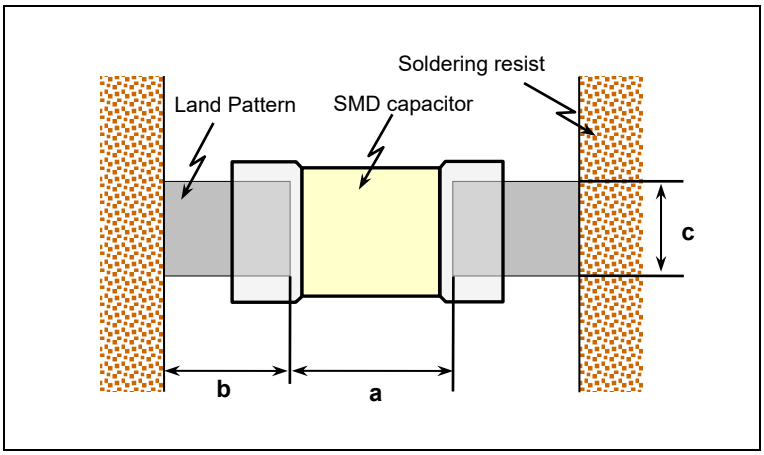
Too much solder amount may increase solder stress and cause crack risk. Insufficient solder amount may reduce adhesive Strength and cause parts falling off PCB. When soldering, confirm that the solder is placed over 0.2mm of the surface of the terminations.



【Recommended Land Pattern Dimensions】

When mounting the capacitor to substrate, it's important to consider that the amount of solder (size of fillet) used has a direct effect upon the capacitor once it's mounted.

1. The greater the amount of solder, the greater the stress to the elements, as this may cause the substrate to break or crack.
2. In the situation where two or more devices are mounted onto a common land, separate the device into exclusive pads by using soldering resist.
3. Land width equal to or less than component. It is permissible to reduce land width to 80% of component width.



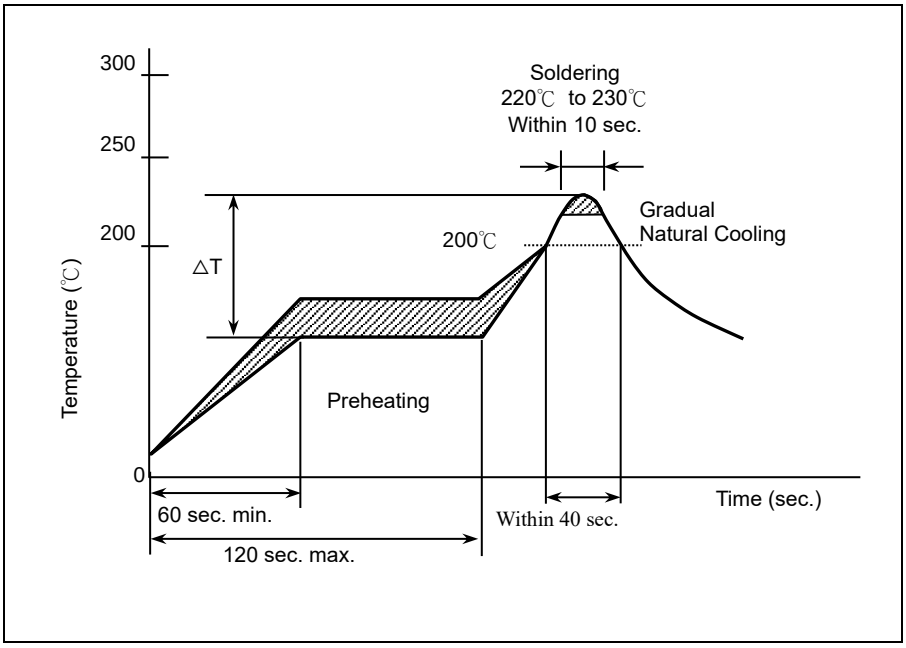
Size mm (EIA)	L x W (mm) (Dimension tolerance)	a (mm)	b (mm)	c (mm)
0603 (0201)	0.6*0.3 (within±0.03)	0.2 to 0.35	0.2 to 0.3	0.2 to 0.4
	0.6*0.3 (±0.05/±0.09)	0.2 to 0.35	0.2 to 0.35	0.25 to 0.4
1005 (0402)	1.0*0.5 (within±0.10)	0.3 to 0.5	0.35 to 0.45	0.4 to 0.6
	1.0*0.5 (±0.15/±0.20)	0.4 to 0.6	0.4 to 0.5	0.5 to 0.7
1608 (0603)	1.6*0.8 (within±0.10)	0.7 to 1.0	0.6 to 0.8	0.7 to 0.8
	1.6*0.8 (±0.15/±0.20/±0.25)	0.8 to 1.1	0.7 to 0.8	0.8 to 1.0
2012 (0805)	2.0*1.25	1.0 to 1.4	0.7 to 0.9	1.2 to 1.4

【Resin Mold】

If a large amount of resin is used for molding the chip, cracks may occur due to contraction stress during curing. To avoid such cracks, use a low shrinkage resin. The insulation resistance of the chip will degrade due to moisture absorption. Use a low moisture absorption resin. Check carefully that the resin does not generate a decomposition gas or reaction gas during the curing process or during normal storage. Such gases may crack the chip capacitor or damage the device itself.

【Soldering Profile for SMT Process with SnPb Solder Paste】

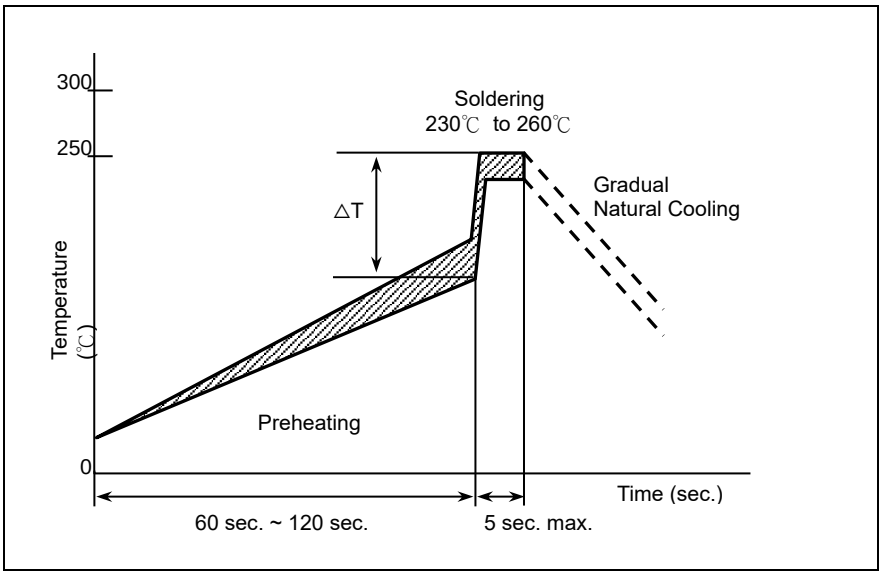
Reflow Soldering



The difference between solder and chip surface should be controlled as following table. The rate of preheat should not exceed 4℃/sec and a target of 2℃/sec is preferred.

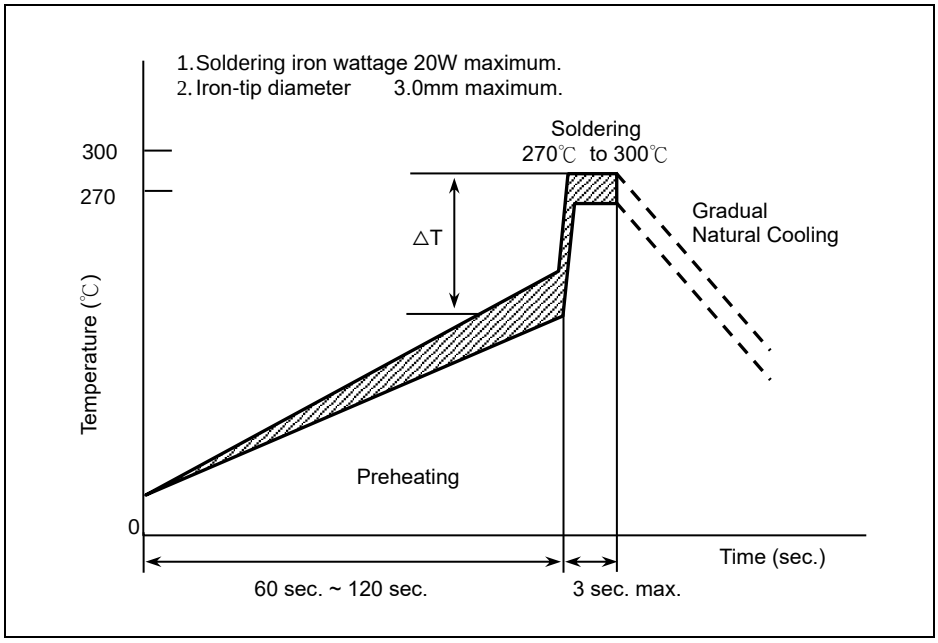
Chip Size	3216 and smaller	3225 and above
Preheating	△T≦150℃	△T≦130℃

Wave Soldering



Chip Size	3216 and smaller	3225 and above
Preheating	△T≦150℃	-

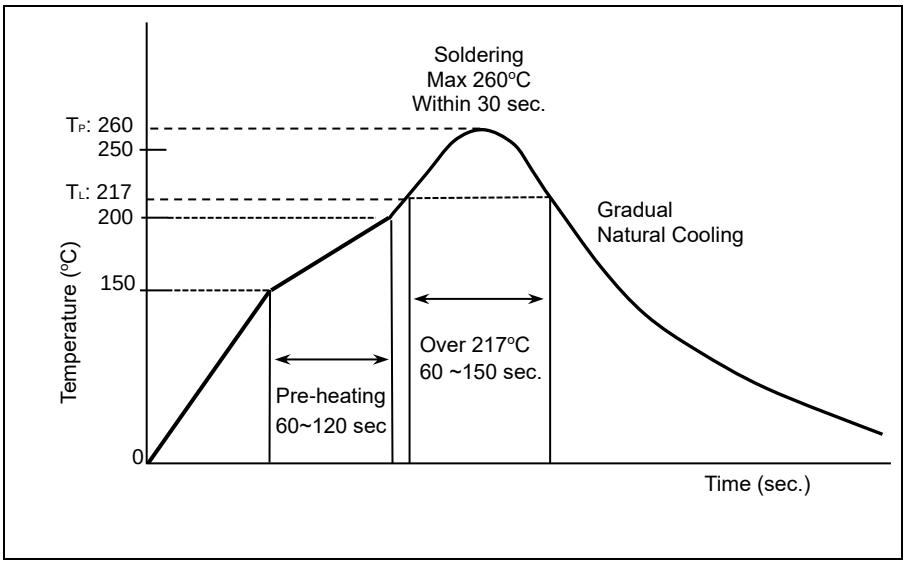
Soldering Iron



Chip Size	3216 and smaller	3225 and above
Preheating	△T≦190℃	△T≦130℃

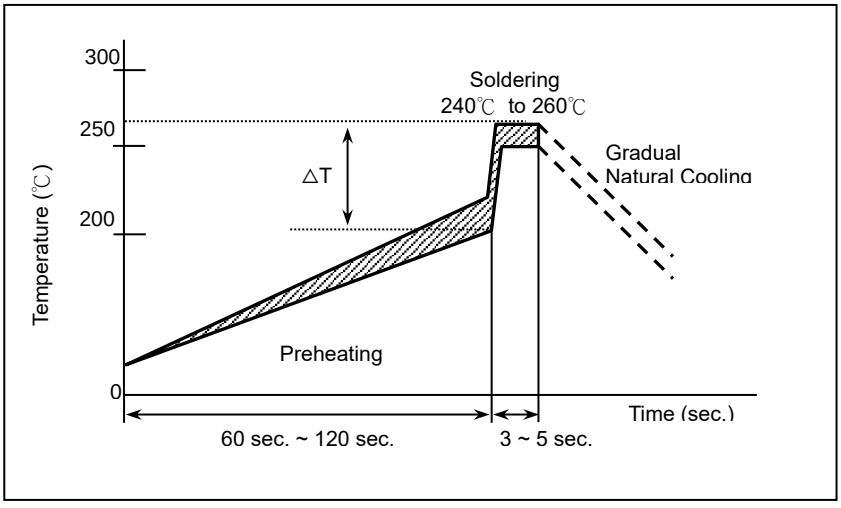
【Soldering】

Reflow Soldering for Lead free (Pb free) Termination



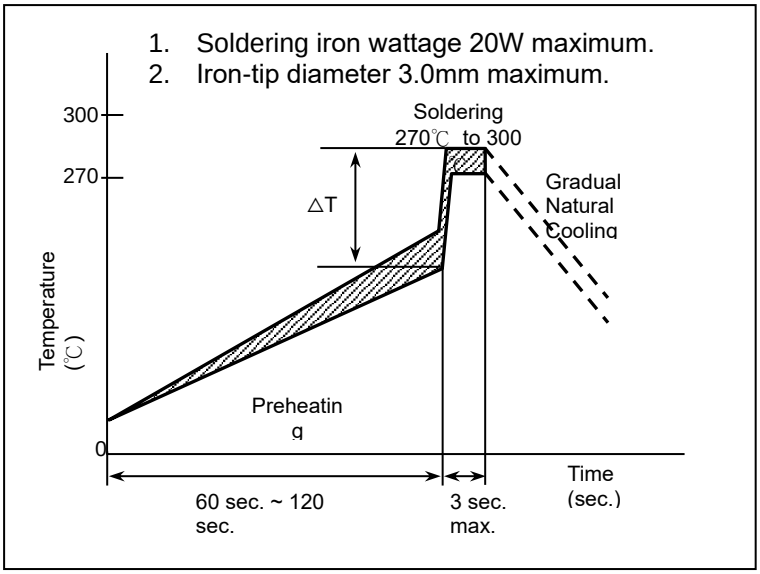
The difference between solder and chip surface should be controlled as following table.
Pre-heating is necessary for all constituents including the PCB to prevent the mechanical damages on MLCC.
The Temperature of the ramp-up rate(TL to TP) is 3□/second max and the ramp-down Rate (TP to TL) is 6□/second max.

Wave Soldering for Lead free Termination



Chip Size	3216 and smaller	3225 and above
Preheating	△T≦150℃	-

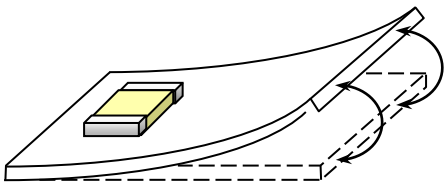
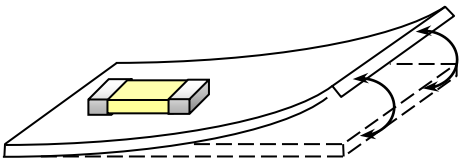
Soldering Iron



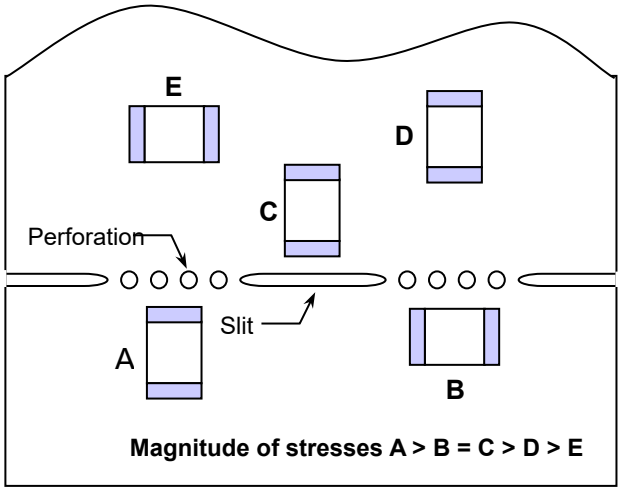
Chip Size	3216 and smaller	3225 and above
Preheating	△T≦190℃	△T≦130℃

【Chip Layout and Breaking PCB】

1. To layout the SMD capacitors for reducing bend stress from board deflection of PCB. The following are examples of Hood and bad layout.

Recommended	Not Recommended
	

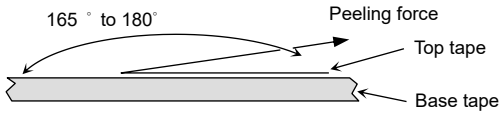
2. When breaking PCB, the layout should be noted that the mechanical stresses are depending on the position of capacitors. The following example shows recommendation for better design.



【Peeling Off Force】

Peeling off force: 0.1N to 1.0 N* in the direction shown as below.

The peeling speed: 300±10 mm/min



1. The taped tape on reel is wound clockwise. The sprocket holes are to the right as the tape is pulled toward the user.
2. There are minimum 150 mm as the leader and minimum 40 mm empty tape as the tail is attached to the end of the tape.

【Disclaimer & Limitation of Use and Applications】

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Limitation

The below application conditions require especially high reliability products to prevent defects that may directly cause damages or loss to third party's life, body or property. If you have any questions regarding this 'Limitation'，you should first contact our sales personnel or application engineers.

1. Aerospace/Aviation equipment
2. 1wheeler, 2wheeler and 3wheeler vehicle
3. Automotive of Transportation equipment
4. Military equipment
5. Atomic energy-related equipment
6. Undersea equipment
7. Medical equipment (excepting Pharmaceutical Affairs Law classification Class1,2)
8. Disaster prevention/crime prevention equipment
9. Power plant control equipment
10. Traffic signal equipment
11. Data-processing equipment
12. Electric heating apparatus，burning equipment
13. Safety equipment
14. Any other applications with the same as or similar complexity or reliability to the applications